



2829

PTO/SB/21 (08-00)

TRANSMITTAL FORM <i>(to be used for all correspondence after initial filing)</i>	Application Number	09/699,466	
	Filing Date	October 31, 2000	
	First Named Inventor	Shunpei YAMAZAKI et al.	
	Group Art Unit	2829	
	Examiner Name	A. Sarkar	
Total Number of Pages in This Submission		Attorney Docket Number	0756-2222

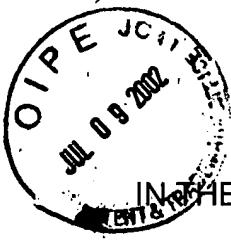
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Firm or Individual name	Eric J. Robinson Robinson Intellectual Property Law Office, P.C. PMB 955 21010 Southbank Street Potomac Falls, VA 20165
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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Shawn
7-24-02

In re Patent Application of)

Art Unit: 2829

Shunpei YAMAZAKI et al.)

Examiner: A. Sarkar

Serial No. 09/699,466)

Filed: October 31, 2000)

For: MEHTOD FOR FABRICATING A)

A SEMICONDUCTOR DEVICE)

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SUPPLEMENTAL AMENDMENT

Honorable Commissioner of Patents

Washington, D.C. 20231

Sir:

Further to the Amendment filed on May 20, 2002 please amend the above-identified application as follows:

IN THE CLAIMS:

Please amend claims 10, 19, 20 and 25 as follows:

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~~10. (Amended) A method according to claim 7, wherein said crystallization promoting material is selected from the group consisting of Fe, Co, Ni, Ru, Rh, Pd, Os, Ir, Pt, Cu and Au.~~

~~19. (Amended) A method according to claim 15, wherein said crystallization promoting material is selected from the group consisting of Fe, Co, Ni, Ru, Rh, Pd, Os, Ir, Pt, Cu and Au.~~

~~20. (Twice Amended) A method for manufacturing a semiconductor device comprising the steps of:
forming a semiconductor film on an insulating surface;
providing a crystallization promoting material onto said semiconductor film;~~